

ZXMS6004FFQ-7

60V N-CHANNEL SELF PROTECTED ENHANCEMENT MODE IntelliFET MOSFET

Compact High Power Dissipation Package

Short Circuit Protection with Auto Restart Overvoltage Protection (Active Clamp) Thermal Shutdown with Auto Restart

Features and Benefits

Logic Level Input (3.3V and 5V)

High Continuous Current Rating

Low Input Current

Overcurrent Protection

Input Protection (ESD)

Product Summary

- Continuous Drain Source Voltage: 60V
- On-State Resistance: 500mΩ
- Nominal Load Current (V_{IN} = 5V): 1.3A
- Clamping Energy: 90mJ

Description

The DIODES[™] ZXMS6004FFQ-7 is a self-protected low side IntelliFET[®] MOSFET with logic level input. It integrates overtemperature, overcurrent, overvoltage (active clamp) and ESD protected logic level functionality. The ZXMS6004FFQ-7 is ideal as a general purpose switch driven from 3.3V or 5V microcontrollers in harsh environments where standard MOSFETs are not rugged enough.

Applications

- Especially suited for loads with a high in-rush current such as lamps and motors
- All types of resistive, inductive and capacitive loads in switching applications
- µC compatible power switches for 12V and 24V DC applications
- Automotive rated
- Replaces electromechanical relays and discrete circuits
- Linear mode capabilities the current-limiting protection circuitry is designed to de-activate at low V_{DS} to minimize on state power dissipation. The maximum DC operating current is therefore determined by the thermal capability of the package/board combination, rather than by the protection circuitry. This does not compromise the product's ability to self-protect at low V_{DS}.



Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
Halogen and Antimony Free. "Green" Device (Note 3)

• The ZXMS6004FFQ-7 is suitable for automotive applications requiring specific change control; this part is AEC-Q101 qualified, PPAP capable, and manufactured in IATF16949 certified facilities.

https://www.diodes.com/quality/product-definitions/

Mechanical Data

- Package: SOT23F
- Package Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 (e3)
- Weight: 0.012 grams (Approximate)

S

Top View

Pin Out

Ordering Information (Note 4)

Part Number Pack	Package	Marking	Iarking Reel Size (inches)	Tape Width (mm)	Packing	
	Fackage	Warking			Qty.	Carrier
ZXMS6004FFQ-7	SOT23F	1K6	7	12	3,000	Reel

Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.

2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

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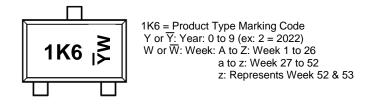
3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

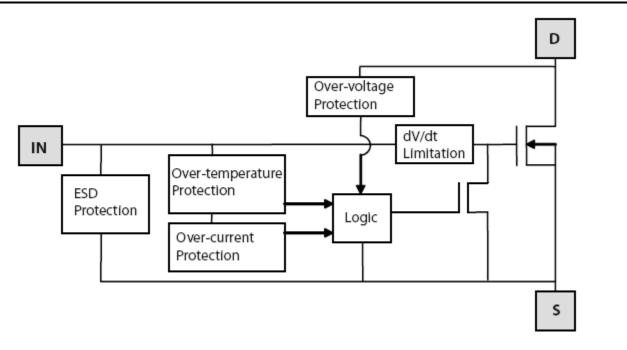
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Marking Information



Functional Block Diagram





Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Units
Continuous Drain-Source Voltage	Vds	60	V
Drain-Source Voltage for Short Circuit Protection	VDS(SC)	36	V
Continuous Input Voltage	Vin	-0.5 +6	V
Continuous Input Current @-0.2V \leq V _{IN} \leq 6V Continuous Input Current @V _{IN} $<$ -0.2V or V _{IN} $>$ 6V	lin	No Limit I _{IN} ≤ 2	mA
Pulsed Drain Current @VIN = 3.3V	Ідм	2	А
Pulsed Drain Current @VIN = 5V	Ідм	2.5	А
Continuous Source Current (Body Diode)	ls	1	А
Pulsed Source Current (Body Diode)	lsм	5	A
Unclamped Single Pulse Inductive Energy T _J = +25°C, I_D = 0.5A, V_{DD} = 24V	Eas	90	mJ
Electrostatic Discharge (Human Body Model)	Vesd	4,000	V
Charged Device Model	V _{CDM}	1,000	V

Thermal Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Units
Power Dissipation @T _A = +25°C (Note 5) Linear Derating Factor	PD	0.83 6.66	W mW/°C
Power Dissipation $@T_A = +25^{\circ}C$ (Note 6) Linear Derating Factor	PD	1.5 12.0	W mW/°C
Thermal Resistance, Junction to Ambient (Note 5)	Reja	150	°C/W
Thermal Resistance, Junction to Ambient (Note 6)	Reja	83	°C/W
Thermal Resistance, Junction to Case (Note 7)	Rejc	44	°C/W
Operating Temperature Range	TJ	-40 to +150	°C
Storage Temperature Range	Tstg	-55 to +150	°C

5. For a device surface mounted on 15mm x 15mm single sided, 1oz weight copper on 1.6mm FR4 board, in still air conditions. 6. For a device surface mounted on 50mm x 50mm single sided, 2oz weight copper on 1.6mm FR4 board, in still air conditions. Notes:

7. Thermal resistance from junction and the mounting surfaces of the drain pins.

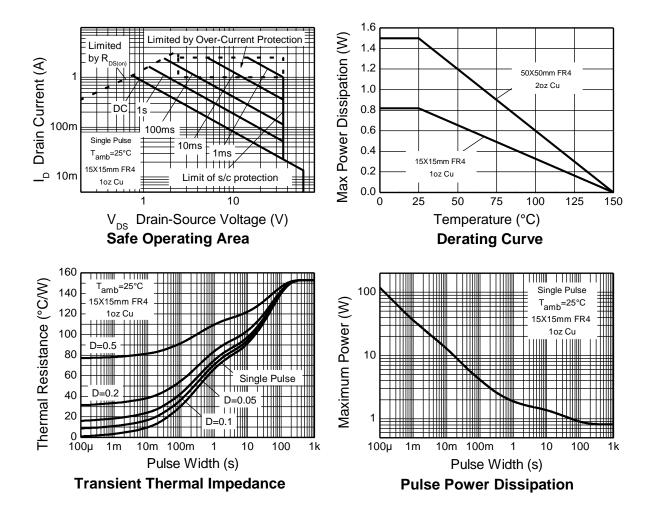
Recommended Operating Conditions

The ZXMS6004FFQ-7 is optimized for use with μ C operating from 3.3V and 5V supplies.

Characteristic	Symbol	Min	Max	Unit
Input Voltage Range	Vin	0	5.5	V
Ambient Temperature Range	TA	-40	+125	°C
High Level Input Voltage for MOSFET to be On	Vін	3	5.5	V
Low Level Input Voltage for MOSFET to be Off	VIL	0	0.7	V
Peripheral Supply Voltage (Voltage to which Load is Referred)	VP	0	36	V



Typical Thermal Characteristics





Notes:

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Static Characteristics	•			•		
Drain-Source Clamp Voltage	VDS(AZ)	60	65	70	V	I _D = 10mA
Off-State Drain Current			—	500	nA	$V_{DS} = 12V, V_{IN} = 0V$
On-State Drain Current	IDSS	_	—	1	μA	$V_{DS} = 36V, V_{IN} = 0V$
Input Threshold Voltage	Vin(th)	0.7	1	1.5	V	$V_{DS} = V_{GS}, I_D = 1mA$
Innut Current	Lu.	_	60	100	μA	$V_{IN} = +3V$
Input Current	lin	_	120	200		$V_{IN} = +5V$
Input Current while Overtemperature Active	—	_	—	220	μA	V _{IN} = +5V
Static Drain-Source On-State Resistance	_	_	400	600	mΩ	$V_{IN} = +3V, I_D = 0.5A$
Static Drain-Source On-State Resistance	RDS(ON)	-	350	500	1112	$V_{IN} = +5V, I_D = 0.5A$
Continuous Droin Current (Note 5)		0.9	—	—		V _{IN} = 3V; T _A = +25°C
Continuous Drain Current (Note 5)	1-	1.0	—	—	A	V _{IN} = 5V; T _A = +25°C
Continuous Droin Current (Note 6)	- ID	1.2	—	—		V _{IN} = 3V; T _A = +25°C
Continuous Drain Current (Note 6)		1.3	—	_		V _{IN} = 5V; T _A = +25°C
Current Limit (Nate 2)	ID(LIM)	0.7	1.7	—	A	$V_{IN} = +3V$
Current Limit (Note 8)		1	2.2	_		$V_{IN} = +5V$
Dynamic Characteristics						
Turn-On Delay Time	t _{D(ON)}	_	5	—	-	
Rise Time	tR	-	10	_		
Turn-Off Delay Time	tD(OFF)	_	45	_	μs	$V_{DD} = 12V, I_D = 0.5A, V_{GS} = 5V$
Fall Time	tF		15	_]	
Overtemperature Protection						
Thermal Overload Trip Temperature (Note 9)	TJT	+150	+175	_	°C	—
Thermal Hysteresis (Note 9)	fF	_	+10	_	°C	_

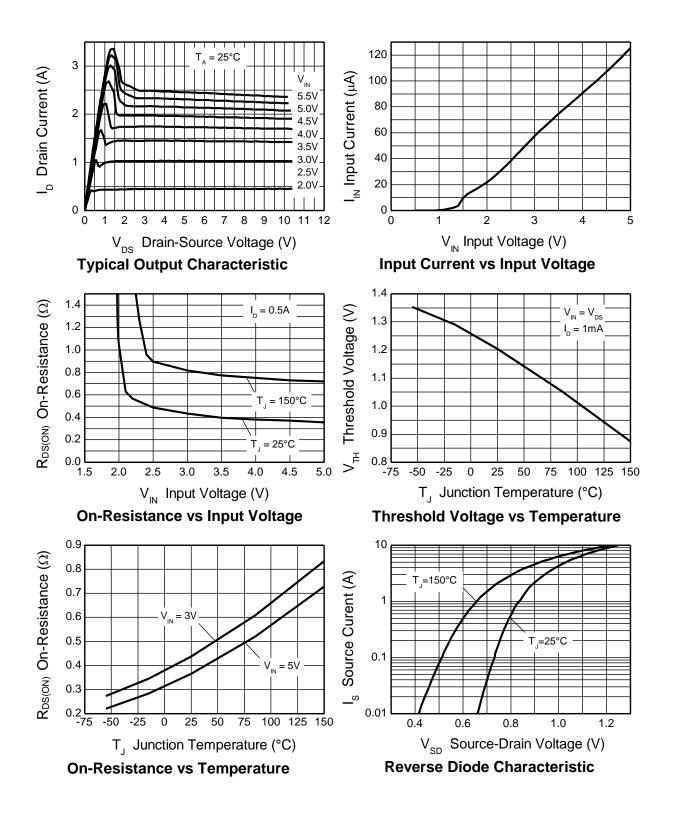
5. For a device surface mounted on 15mm x 15mm single sided, 1oz weight copper on 1.6mm FR4 board, in still air conditions. 6. For a device surface mounted on 50mm x 50mm single sided, 2oz weight copper on 1.6mm FR4 board, in still air conditions.

7. Thermal resistance from junction and the mounting surfaces of the drain pins.
8. The drain current is restricted only when the device is in saturation (see graph 'Typical Output Characteristic'). This allows the device to be used in the fully on-state without interference from the current limit. The device is fully protected at all drain currents, as the low power dissipation generated outside

9. Overtemperature protection is designed to prevent device from destruction under fault conditions. Fault conditions are considered as "outside" normal operating range, so this part is not designed to withstand overtemperature for extended periods.

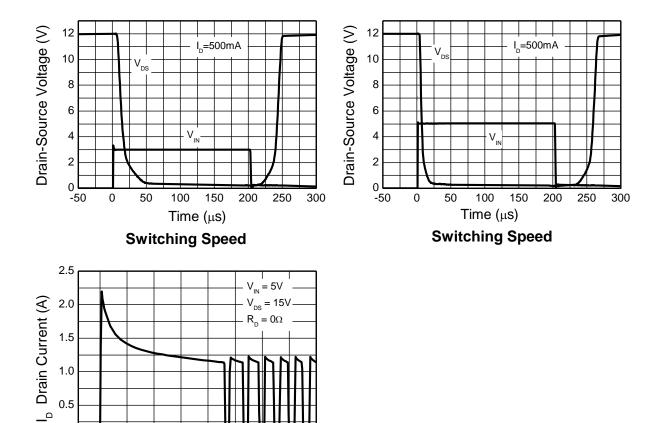


Typical Performance Characteristics





Typical Performance Characteristics (continued)



1.0

0.5

0.0

0

5

10

Time (ms)

Typical Short Circuit Protection

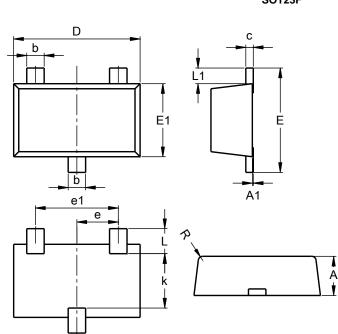
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20



Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

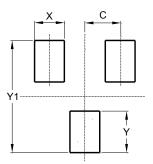


[50)T23F				
Dim						
			Тур			
Α	0.80	1.00	0.90			
A1	0.00	0.10	0.01			
b	0.35	0.50	0.44			
С	0.10	0.20	0.16			
D	2.80	3.00	2.90			
е	0.95 REF					
e1	1.90 REF					
Е	2.30	2.50	2.40			
E1	1.50	1.70	1.65			
k	1.20					
L	0.30	0.65	0.50			
L1	0.30	0.50	0.40			
R	0.05	0.15	-			
A	All Dimensions in mm					

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT23F



Dimensions	Value (in mm)		
С	0.95		
Х	0.80		
Y	1.110		
Y1	3.000		

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